Single Unbuffered Inverter

The NL17SZU04 is a single unbuffered inverter in two tiny footprint package. The device performs much as LCX multi-gate products in speed and drive.

Features

- Tiny SOT-353 and SOT-553 Packages
- Source/Sink ± 16 mA at 4.5 V V_{CC}
- Over-Voltage Tolerant Inputs and Outputs
- Pin For Pin with NC7SZU04P5X, TC7SZU04FU and TC7SZU04AFE
- Chip Complexity: FETs = 20
- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Pb-Free Packages are Available

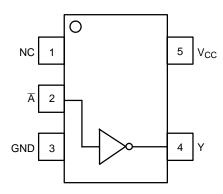


Figure 1. Pinout (Top View)

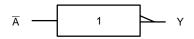


Figure 2. Logic Symbol



http://onsemi.com



SOT-353/SC70-5/SC-88A DF SUFFIX CASE 419A

MARKING DIAGRAMS



d = Date Code



SOT-553 XV5 SUFFIX CASE 463B



L6 = Device Marking
D = One Digit Date Code

PIN ASSIGNMENT

Pin	Function
1	NC
2	Ā
3	GND
4	Y
5	V _{CC}

FUNCTION TABLE

	Output Y = A
Input	Y = A
Α	Y
L	Н
Н	L

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Symbol	Parame	eter	Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
V _{IN}	DC Input Voltage	-0.5 to +7.0	V	
V _{OUT}	DC Output Voltage		-0.5 to +7.0	V
I _{IK}	DC Input Diode Current		-50	mA
I _{OK}	DC Output Diode Current	-50	mA	
I _{OUT}	DC Output Sink Current	±50	mA	
I _{CC}	DC Supply Current per Supply Pin	±100	mA	
T _{STG}	Storage Temperature Range	-65 to +150	°C	
T _L	Lead Temperature, 1 mm from Case for 10	260	°C	
T_J	Junction Temperature Under Bias		+150	°C
$\theta_{\sf JA}$	Thermal Resistance	SOT-353 (Note 1) SOT-553	350 496	°C/W
P _D	Power Dissipation in Still Air at 85°C	SOT-353 SOT-553	186 135	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	Class IC Class A N/A	V

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
- 2. Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.
- 3. Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parame	Min	Max	Unit	
V _{CC}	DC Supply Voltage	(Operating) Data Retention Only	1.65 1.5	5.5 5.5	V
V _{IN}	DC Input Voltage		0	5.5	V
V _{OUT}	DC Output Voltage		0	5.5	V
T _A	Operating Temperature Range		-40	+85	°C
t _r , t _f	Input Rise and Fall Time	$V_{CC} = 3.0 \text{ V} \pm 0.3 \text{ V} $ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0	100 20	ns/V

DC ELECTRICAL CHARACTERISTICS

			V _{CC}	T	T _A = 25°C		-40°C ≤	$T_A \leq 85^{\circ}C$	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
V _{IH}	High-Level Input Voltage		1.65 to 1.85	0.85 V _{CC}			0.85 V _{CC}		V
			2.3 to 5.5	0.8 V _{CC}			0.8 V _{CC}		1
V _{IL}	Low-Level Input Voltage		1.65 to 1.85			0.15 V _{CC}		0.15 V _{CC}	V
			2.3 to 5.5			0.2 V _{CC}		0.2 V _{CC}	
V _{OH}	High-Level Output Voltage V _{IN} = V _{IL} or V _{IH}	$I_{OH} = -100 \mu A$ $I_{OH} = -3 \text{ mA}$	1.65 to 5.5 1.65	V _{CC} - 0.1 1.29	V _{CC} 1.52		V _{CC} - 0.1 1.29		V
		$I_{OH} = -4 \text{ mA}$	2.3	1.9	2.1		1.9		
		$I_{OH} = -6 \text{ mA}$	2.7	2.2	2.4		2.2		
		$I_{OH} = -8 \text{ mA}$	3.0	2.4	2.7		2.4		
		I _{OH} = -12 mA	3.0	2.3	2.5		2.3		
		I _{OH} = -16 mA	4.5	3.8	4.0		3.8		
V _{OL}	Low-Level Output Voltage V _{IN} = V _{IH} or V _{OH}	I_{OL} = 100 μ A I_{OL} = 3 mA	1.65 to 5.5 1.65		0.08	0.1 0.24		0.1 0.24	V
	- III - III OH	I _{OL} = 4 mA	2.3		0.20	0.3		0.3	
		I _{OL} = 6 mA	2.7		0.22	0.4		0.4	
		I _{OL} = 8 mA	3.0		0.28	0.4		0.4	
		I _{OL} = 12 mA	3.0		0.38	0.55		0.55	
		I _{OL} = 16 mA	4.5		0.42	0.55		0.55	
I _{IN}	Input Leakage Current	$V_{IN} = V_{CC}$ or GND	0 to 5.5			± 0.1		±1.0	μΑ
I _{OFF}	Power Off–Output Leakage Current	V _{OUT} = 5.5 V	0			1		10	μΑ
Icc	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	1.65 to 5.5			1		10	μΑ

AC ELECTRICAL CHARACTERISTICS $t_R = t_F = 3.0 \text{ ns}$

			V _{CC}	T _A =	25°C	-40°C ≤	Γ _A ≤ 85°C	
Symbol	Parameter	Condition	(V)	Min	Max	Min	Max	Unit
t _{PLH}	Propagation Delay	$R_L = 1 \text{ M}\Omega$, $C_L = 15 \text{ pF}$	1.8 ± 0.15	1.0	11.7	1.0	12.1	ns
t _{PHL}	(Figure 3 and 4)	$R_L = 1 M\Omega, C_L = 15 pF$	2.5 ± 0.2	0.8	6.2	0.8	6.5	
		$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	3.3 ± 0.3	0.5	4.5	0.5	4.8	
		$R_L = 500 \Omega, C_L = 50 pF$		1.0	6.0	1.0	6.5	
		$R_L = 1 \text{ M}\Omega$, $C_L = 15 \text{ pF}$	5.0 ± 0.5	0.5	3.9	0.5	1.0	
		$R_L = 500 \Omega, C_L = 50 pF$		0.8	5.0	0.8	5.5	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	4.5	pF
C _{PD}	Power Dissipation Capacitance	10 MHz, V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	6.5	pF
	(Note 5)	10 MHz, $V_{CC} = 5.5 \text{ V}$, $V_{I} = 0 \text{ V}$ or V_{CC}	10	

^{5.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

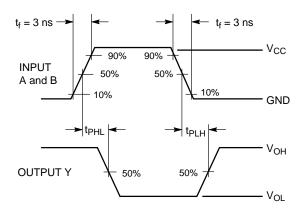
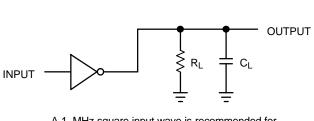


Figure 3. Switching Waveform



A 1-MHz square input wave is recommended for propagation delay tests.

Figure 4. Test Circuit

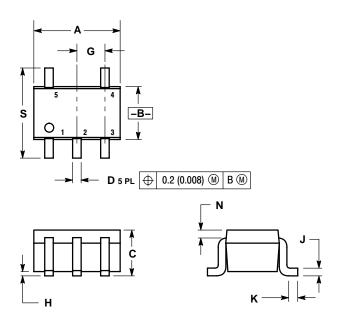
DEVICE ORDERING INFORMATION

		Device Nomenclature							
Device Order Number	Logic Circuit Indicator	No. of Gates per Package	Temp Range Identifier	Technology	Device Function	Package Suffix	Tape and Reel Suffix	Package Type	Tape and Reel Size [†]
NL17SZU04DFT2	NL	1	7	SZ	U04	DF	T2	SOT-353/ SC70-5/ SC-88A	178 mm, 3000 Unit
NL17SZU04DFT2G	NL	1	7	SZ	U04	DF	T2	SOT-353/ SC70-5/ SC-88A (Pb-Free)	178 mm, 3000 Unit
NL17SZU04XV5T2	NL	1	7	SZ	U04	XV5	T2	SOT-553*	178 mm, 4000 Unit

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*All Devices in Package SOT553 are Inherently Pb–Free.

PACKAGE DIMENSIONS

SOT-353 **DF SUFFIX** 5-LEAD PACKAGE CASE 419A-02 ISSUE G



NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

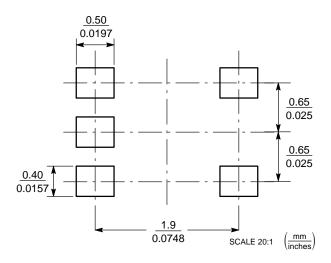
 2. CONTROLLING DIMENSION: INCH.

 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.

 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.071	0.087	1.80	2.20	
В	0.045	0.053	1.15	1.35	
С	0.031	0.043	0.80	1.10	
D	0.004	0.012	0.10	0.30	
G	0.026	BSC	0.65 BSC		
Н		0.004		0.10	
J	0.004	0.010	0.10	0.25	
K	0.004	0.012	0.10	0.30	
N	0.008	REF	0.20 REF		
S	0.079	0.087	2.00	2.20	

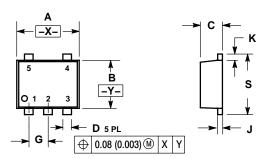
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SOT-553 XV5 SUFFIX 5-LEAD PACKAGE CASE 463B-01 **ISSUE A**



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETERS 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.50	1.70	0.059	0.067
В	1.10	1.30	0.043	0.051
С	0.50	0.60	0.020	0.024
D	0.17	0.27	0.007	0.011
G	0.50	BSC	0.020	BSC
J	0.08	0.18	0.003	0.007
K	0.10	0.30	0.004	0.012
S	1.50	1.70	0.059	0.067

PIN 1. BASE 1 EMITTER 1/2 3 BASE 2

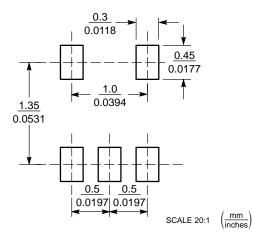
COLLECTOR 2 5. COLLECTOR 1

STYLE 2: PIN 1. CATHODE

2. ANODE 3. CATHODE

CATHODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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